

PHOTOCOUPLER PS9122

1 Mbps OPEN COLLECTOR OUTPUT TYPE 5-PIN SOP (SO-5) HIGH-SPEED PHOTOCOUPLER

-NEPOC Series-

DESCRIPTION

The PS9122 is an optical coupled high-speed, active low type isolator containing a GaAlAs LED on the input side and a photodiode and a signal processing circuit on the output side on one chip.

The PS9122 is a high-speed digital output type photocoupler designed specifically for low circuit current.

The PS9122 is in 5-pin plastic SOP (Small Outline Package) and is suitable for high density application.

FEATURES

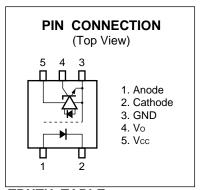
· Supply Voltage

N rank: Vcc = 3.3 VL rank: Vcc = 5 V

- Pulse width distortion (tphl tplh = 200 ns MAX.)
- Small package (SO-5)
- High-speed (1 Mbps)
- High isolation voltage (BV = 3 750 Vr.m.s.)
- · Open collector output
- Embossed tape product: PS9122-F3: 2 500 pcs/reel
- Pb-Free product
- Safety standards
 - UL approved: File No. E72422
 - DIN EN60747-5-2 (VDE0884 Par2) approved No.40008902 (option)

APPLICATIONS

- PoE (Power over Ethernet)
- Measurement equipment
- FA Network

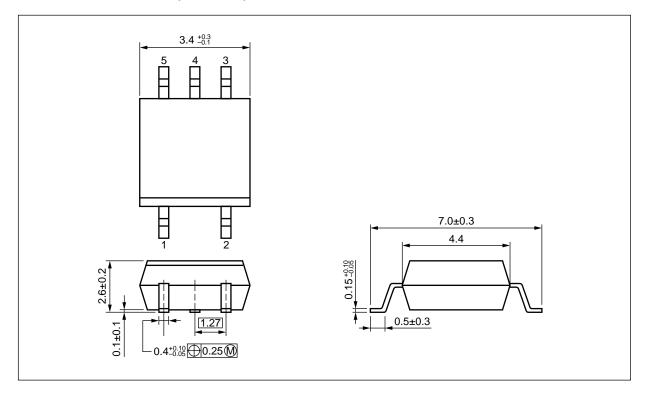


TRUTH TABLE

LED	Output
ON	L
OFF	Н

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

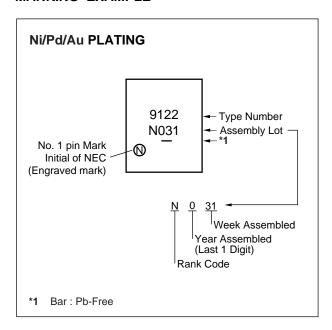
PACKAGE DIMENSIONS (UNIT: mm)



*** PHOTOCOUPLER CONSTRUCTION**

Parameter	Unit (MIN.)
Air Distance	4.2 mm
Outer Creepage Distance	4.2 mm
Isolation Distance	0.2 mm

★ MARKING EXAMPLE



*** ORDERING INFORMATION**

Part Number	Order Number	Rank	Solder Plating Specification	Packing Style	Safety Standards Approval	Application *1 Part Number
PS9122	PS9122-AX	N*2 L*3	Pb-Free (Ni/Pd/Au)	20 pcs (Tape 20 pcs cut)	Standard products (UL approved)	PS9122
PS9122-F3	PS9122-F3-AX	N*2 L*3		Embossed Tape 2 500 pcs/reel		
PS9122-V	PS9122-V-AX	N*2 L*3		20 pcs (Tape 20 pcs cut)	DIN EN60747-5-2 (VDE0884 Part2)	
PS9122-V-F3	PS9122-V-F3-AX	N*2 L*3		Embossed Tape 2 500 pcs/reel	approved (Option)	

^{*1} For the application of the Safety Standard, following part number should be used.

^{*2} N rank: Vcc = 3.3 V

^{*3} L rank: Vcc = 5 V

ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current*1	lF	25	mA
	Reverse Voltage	VR	5	V
Detector	Supply Voltage	Vcc	7	V
	Output Voltage	Vo	7	V
	Output Current	lo	20	mA
	Power Dissipation*2	Pc	40	mW
Isolation	Voltage ^{*3}	BV	3 750	Vr.m.s.
Operating Ambient Temperature		TA	-40 to +100	°C
Storage Temperature		T _{stg}	-55 to +125	°C

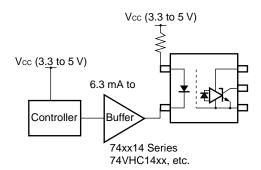
- ***1** Reduced to 0.17 mA/°C at T_A = 25°C or more.
- ***2** Applies to output pin Vo (collector pin). Reduced to 1.5 mW/°C at T_A = 80°C or more.
 - *3 AC voltage for 1 minute at $T_A = 25$ °C, RH = 60% between input and output. Pins 1-2 shorted together, 3-5 shorted together.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit	
Low Level Input Voltage	V _F L	0		0.8	V	
High Level Input Current		lғн	6.3	10	12.5	mA
Supply Voltage	N rank	Vcc	2.7	3.3	3.6	V
	L rank		4.5	5.0	5.5	
TTL (R _L = 1 k Ω , loads)		N			3	
Pull-up Resistor		R∟	330		4 k	Ω

★ DRIVER CIRCUIT

It is recommended to use some buffer for low output current controller, especially in the case of low Vcc, otherwise to confirm that enough input current is supplied from controller.



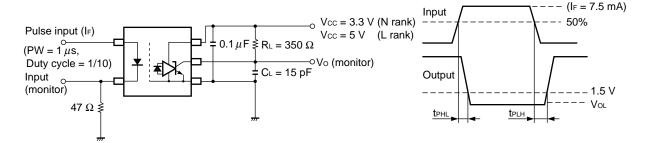
ELECTRICAL CHARACTERISTICS 1: N rank ($T_A = -40 \text{ to } +100^{\circ}\text{C}$, unless otherwise specified)

	Parameter	Symbol	Conditions	MIN.	TYP. ^{*1}	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA, TA = 25°C		1.6	1.8	V
	Reverse Current	IR	VR = 3 V, TA = 25°C			10	μА
	Terminal Capacitance	Ct	V = 0 V, f = 1 MHz, T _A = 25°C		30		pF
Detector	High Level Output Current	Іон	Vcc = Vo = 3.3 V, V _F = 0.8 V		1	100	μA
	Low Level Output Voltage*2	Vol	Vcc = 3.3 V, I _F = 5 mA, I _{OL} = 10 mA		0.2	0.6	V
	High Level Supply Current	Іссн	Vcc = 3.3 V, I _F = 0 mA, Vo = Open			2	mA
	Low Level Supply Current	Iccl	Vcc = 3.3 V, I _F = 10 mA, Vo = Open			3	
Coupled	Threshold Input Current $(H \rightarrow L)$	IFHL	$Vcc = 3.3 \text{ V}, Vo = 0.8 \text{ V}, R_L = 350 \Omega$		2	5	mA
	Isolation Resistance	Ri-o	V _{I-O} = 1 kV _{DC} , RH = 40 to 60%, T _A = 25°C	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz, T _A = 25°C		0.6		pF
	Propagation Delay Time $(H \rightarrow L)^{*3}$	t PHL	$\label{eq:Vcc} \begin{array}{l} \mbox{Vcc} = 3.3 \mbox{ V, RL} = 350 \ \Omega, \mbox{ Ir} = 7.5 \mbox{ mA}, \\ \mbox{VTHHL} = \mbox{VTHLH} = 1.5 \mbox{ V} \end{array}$			500	ns
	Propagation Delay Time $(L \rightarrow H)^{*3}$	t PLH				700	
	Rise Time	tr			60		ns
	Fall Time	t _f			70		
	Pulse Width Distortion (PWD)*3	tphl-tplh				200	ns
	Common Mode Transient Immunity at High Level Output* ⁴	СМн	$\label{eq:Vcc} \begin{array}{l} \mbox{Vcc} = 3.3 \ \mbox{V}, \ \mbox{R}_L = 350 \ \Omega, \ \mbox{T}_A = 25^{\circ}\mbox{C}, \\ \mbox{I}_F = 0 \ \mbox{mA}, \ \mbox{Vo} > 2.0 \ \mbox{V}, \ \mbox{Vcm} = 1.0 \ \mbox{kV} \end{array}$	15	20		kV/μs
	Common Mode Transient Immunity at Low Level Output*4	CML	$V_{CC} = 3.3 \text{ V}, \ R_L = 350 \ \Omega, \ T_A = 25^{\circ}\text{C},$ $I_F = 7.5 \ mA, \ V_O < 0.8 \ V, \ V_{CM} = 1.0 \ kV$	15	20		

ELECTRICAL CHARACTERISTICS 2: L rank ($T_A = -40 \text{ to } +100^{\circ}\text{C}$, unless otherwise specified)

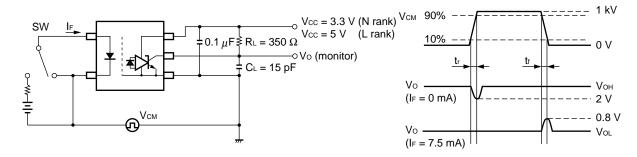
	Parameter	Symbol	Conditions	MIN.	TYP. ^{*5}	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA, TA = 25°C		1.6	1.8	V
	Reverse Current	IR	VR = 3 V, TA = 25°C			10	μА
	Terminal Capacitance	Ct	V = 0 V, f = 1 MHz, T _A = 25°C		30		pF
Detector	High Level Output Current	Іон	Vcc = Vo = 5 V, V _F = 0.8 V		1	100	μА
	Low Level Output Voltage*6	Vol	Vcc = 5 V, IF = 5 mA, IoL = 13 mA		0.2	0.6	V
	High Level Supply Current	Іссн	Vcc = 5 V, I _F = 0 mA, Vo = Open			2.5	mA
	Low Level Supply Current	Iccl	Vcc = 5 V, I _F = 10 mA, Vo = Open			3.5	
Coupled	Threshold Input Current $(H \rightarrow L)$	IFHL	$Vcc = 5 \text{ V}, Vo = 0.8 \text{ V}, R_L = 350 \Omega$		2	5	mA
	Isolation Resistance	Ri-o	V _{I-O} = 1 kV _{DC} , RH = 40 to 60%, T _A = 25°C	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz, T _A = 25°C		0.6		pF
	Propagation Delay Time $(H \rightarrow L)^{*7}$	t PHL	$\label{eq:Vcc} \begin{array}{l} \mbox{Vcc} = 5 \mbox{ V, RL} = 350 \ \Omega, \mbox{ If } = 7.5 \mbox{ mA}, \\ \mbox{VTHHL} = \mbox{VTHLH} = 1.5 \mbox{ V} \end{array}$			500	ns
	Propagation Delay Time $(L \rightarrow H)^{+7}$	t PLH				700	
	Rise Time	tr			60		ns
	Fall Time	t _f			70		
	Pulse Width Distortion (PWD)*7	tphl-tplh				200	ns
	Common Mode Transient Immunity at High Level Output*8	СМн	$\label{eq:Vcc} \begin{array}{l} \mbox{Vcc} = 5 \mbox{ V, RL} = 350 \ \Omega, \mbox{ TA} = 25 \mbox{°C}, \\ \mbox{IF} = 0 \mbox{ mA, Vo} > 2.0 \mbox{ V, VcM} = 1.0 \mbox{ kV} \\ \end{array}$	15	20		kV/μ
	Common Mode Transient Immunity at Low Level Output ^{*8}	CML	Vcc = 5 V, R_L = 350 Ω, T_A = 25°C, I_F = 7.5 mA, Vo < 0.8 V, VcM = 1.0 kV	15	20		

- *1, 5. Typical values at $T_A = 25^{\circ}C$
- *2, 6. Because VoL of 2 V or more may be output when LED current input and when output supply of Vcc = 2 V more or less, it is important to confirm the characteristics (operation with the power supply on and off) during design, before using this device.
- *3, 7. Test circuit for propagation delay time



Remark C_L includes probe and stray wiring capacitance.

*4, 8. Test circuit for common mode transient immunity

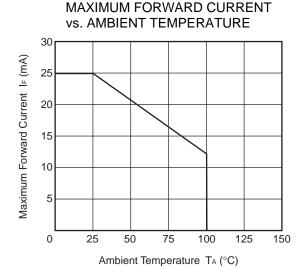


Remark CL includes probe and stray wiring capacitance.

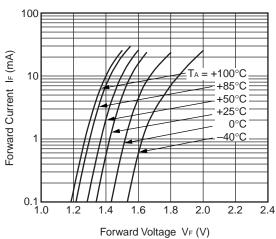
★ USAGE CAUTIONS

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. By-pass capacitor of 0.1 μ F is used between Vcc and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
- 3. Avoid storage at a high temperature and high humidity.

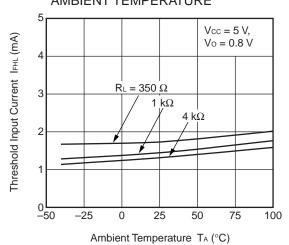
★ TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)



FORWARD CURRENT vs. FORWARD VOLTAGE

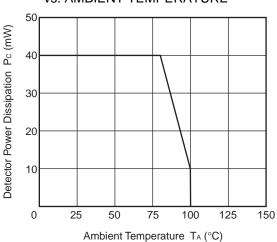


THRESHOLD INPUT CURRENT vs. AMBIENT TEMPERATURE

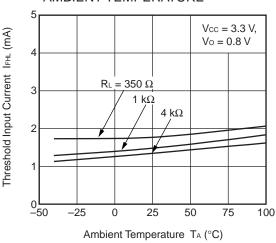


Remark The graphs indicate nominal characteristics.

DETECTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE

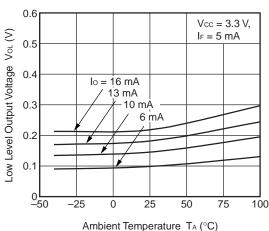


THRESHOLD INPUT CURRENT vs. AMBIENT TEMPERATURE

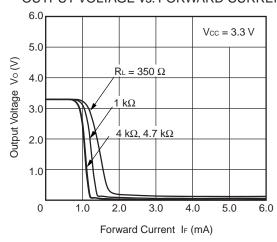


SUPPLY CURRENT vs. AMBIENT TEMPERATURE 3.0 High Level Supply Current Icch (mA) Low Level Supply Current IccL (mA) Iccl (Vcc = 3.3 V, IF = 10 mA) 2.5 2.0 ICCH ($Vcc = 3.3 \text{ V}, I_F = 0 \text{ mA}$) 1.5 1.0 0.5 0 _50 25 100 -2575 Ambient Temperature TA (°C)



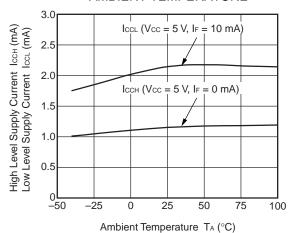


OUTPUT VOLTAGE vs. FORWARD CURRENT

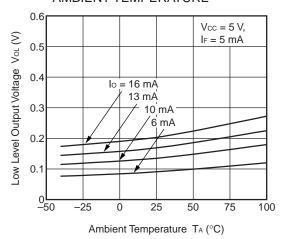


Remark The graphs indicate nominal characteristics.

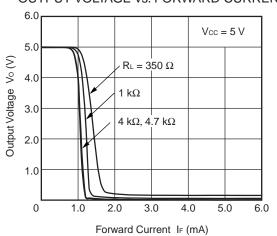
SUPPLY CURRENT vs. AMBIENT TEMPERATURE



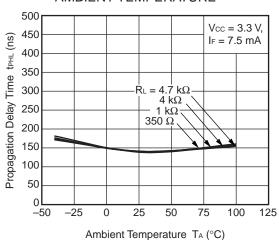
LOW LEVEL OUTPUT VOLTAGE vs. AMBIENT TEMPERATURE



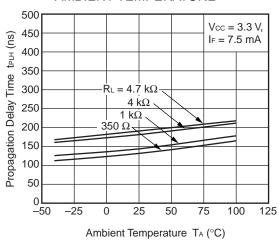
OUTPUT VOLTAGE vs. FORWARD CURRENT



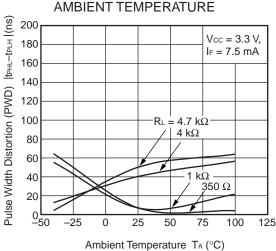
PROPAGATION DELAY TIME vs. AMBIENT TEMPERATURE



PROPAGATION DELAY TIME vs. AMBIENT TEMPERATURE

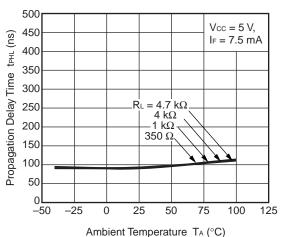


PULSE WIDTH DISTORTION vs.

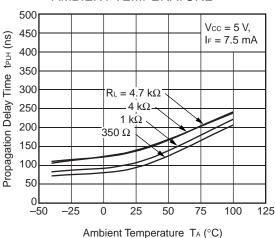


Remark The graphs indicate nominal characteristics.

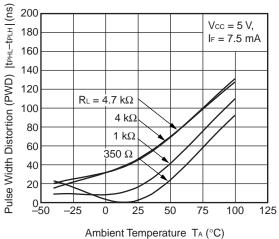
PROPAGATION DELAY TIME vs. AMBIENT TEMPERATURE



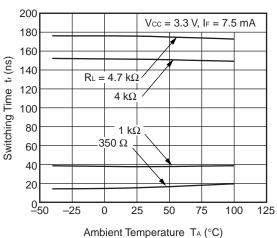
PROPAGATION DELAY TIME vs. AMBIENT TEMPERATURE



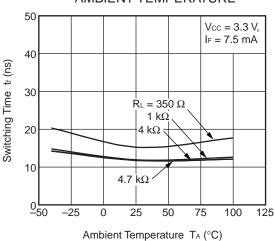
PULSE WIDTH DISTORTION vs. AMBIENT TEMPERATURE



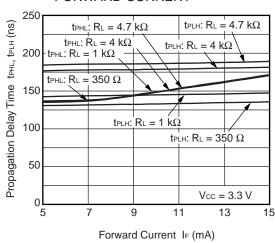




SWITCHING TIME vs. AMBIENT TEMPERATURE

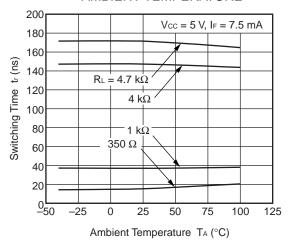


PROPAGATION DELAY TIME vs. FORWARD CURRENT

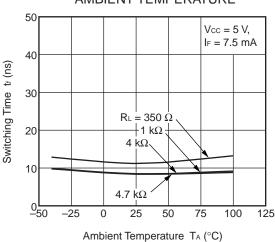


Remark The graphs indicate nominal characteristics.

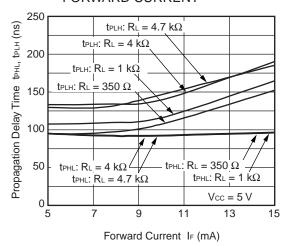
SWITCHING TIME vs. AMBIENT TEMPERATURE



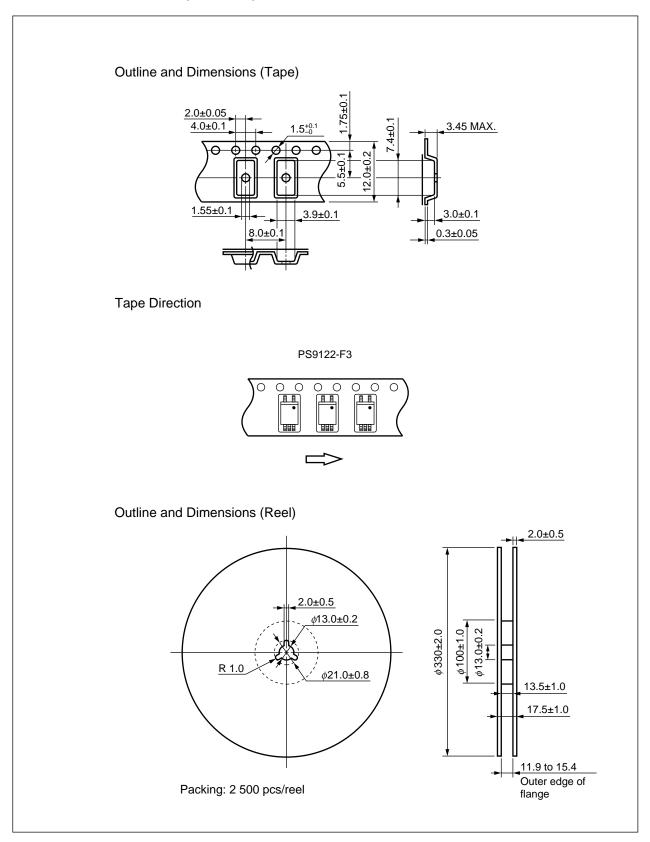
SWITCHING TIME vs. AMBIENT TEMPERATURE



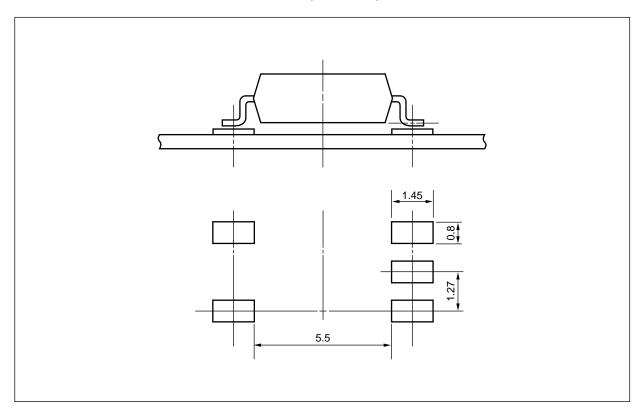
PROPAGATION DELAY TIME vs. FORWARD CURRENT



TAPING SPECIFICATIONS (UNIT: mm)



* RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

· Peak reflow temperature 260C or below (package surface temperature)

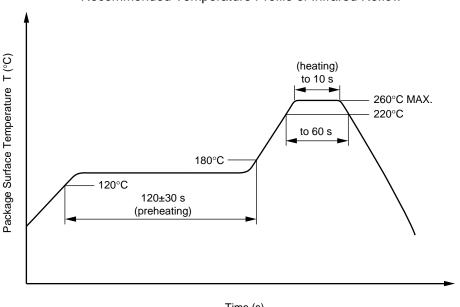
· Time of peak reflow temperature 10 seconds or less • Time of temperature higher than 220C 60 seconds or less

• Time to preheat temperature from 120 to 180C 120±30 s Number of reflows Three

 Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

 Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

· Preheating conditions 120C or below (package surface temperature)

· Number of times One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount ofchlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

• Peak Temperature (ead part temperature) 350°C or below · Time (each pins) 3 seconds or less

 Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead
- (b) Please be sure that the temperature of the package would not be heated over 100°C

(4) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

* SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Speck	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/100/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.5 \times U_{IORM}, P_d < 5 \ pC$	Ulorm Upr	707 1 061	V _{peak} V _{peak}
Test voltage (partial discharge test, procedure b for all devices) $U_{pr} = 1.875 \times U_{IORM}, P_d < 5 \; pC$	Upr	1 326	V _{peak}
Highest permissible overvoltage	Utr	6 000	V _{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	СТІ	175	
Material group (DIN EN 60664-1 VDE0110 Part 1)		III a	
Storage temperature range	T _{stg}	-55 to +125	C
Operating temperature range	TA	-40 to +100	C
Isolation resistance, minimum value V₁o = 500 V dc at TA = 25℃ V₁o = 500 V dc at TA MAX. at least 100℃	Ris MIN. Ris MIN.	10 ¹² 10 ¹¹	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I _F , Psi = 0) Power (output or total power dissipation) Isolation resistance	Tsi Isi Psi	150 200 300	℃ mA mW
Vio = 500 V dc at TA = Tsi	Ris MIN.	10 ⁹	Ω

- The information in this document is current as of March, 2010. The information is subject to change
 without notice. For actual design-in, refer to the latest publications of NEC Electronics data sheets,
 etc., for the most up-to-date specifications of NEC Electronics products. Not all products and/or
 types are available in every country. Please check with an NEC Electronics sales representative for
 availability and additional information.
- No part of this document may be copied or reproduced in any form or by any means without the prior
 written consent of NEC Electronics. NEC Electronics assumes no responsibility for any errors that may
 appear in this document.
- NEC Electronics does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC Electronics products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Electronics or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative
 purposes in semiconductor product operation and application examples. The incorporation of these
 circuits, software and information in the design of a customer's equipment shall be done under the full
 responsibility of the customer. NEC Electronics assumes no responsibility for any losses incurred by
 customers or third parties arising from the use of these circuits, software and information.
- While NEC Electronics endeavors to enhance the quality and safety of NEC Electronics products, customers agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. In addition, NEC Electronics products are not taken measures to prevent radioactive rays in the product design. When customers use NEC Electronics products with their products, customers shall, on their own responsibility, incorporate sufficient safety measures such as redundancy, fire-containment and anti-failure features to their products in order to avoid risks of the damages to property (including public or social property) or injury (including death) to persons, as the result of defects of NEC Electronics products.
- NEC Electronics products are classified into the following three quality grades: "Standard", "Special" and
 "Specific".

The "Specific" quality grade applies only to NEC Electronics products developed based on a customerdesignated "quality assurance program" for a specific application. The recommended applications of an NEC Electronics product depend on its quality grade, as indicated below. Customers must check the quality grade of each NEC Electronics product before using it in a particular application.

- "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots.
- "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support).
- "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC Electronics products is "Standard" unless otherwise expressly specified in NEC Electronics data sheets or data books, etc. If customers wish to use NEC Electronics products in applications not intended by NEC Electronics, they must contact an NEC Electronics sales representative in advance to determine NEC Electronics' willingness to support a given application.

(Note)

- (1) "NEC Electronics" as used in this statement means NEC Electronics Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC Electronics products" means any product developed or manufactured by or for NEC Electronics (as defined above).

M8E0904E

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
- Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush,or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.